



TF252TH

N-Channel JFET 20V, 140 to 350 μ A, 1.4mS, VTFP

ON Semiconductor®

<http://onsemi.com>

Features

- High gain : $GV=1.0\text{dB}$ typ ($V_{CC}=2\text{V}$, $R_L=2.2\text{k}\Omega$, $C_{in}=5\text{pF}$, $V_{IN}=10\text{mV}$, $f=1\text{kHz}$)
- Ultrasmall package facilitates miniaturization in end products
- Best suited for use in electret condenser microphone for audio equipments and telephones
- Excellent voltage characteristics
- Excellent transient characteristics
- Adoption of FBET process
- Halogen free compliance

Specifications

Absolute Maximum Ratings at $T_a=25^\circ\text{C}$

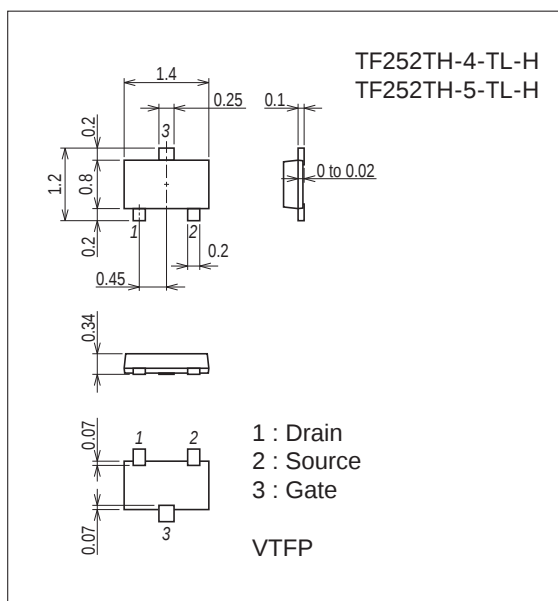
Parameter	Symbol	Conditions	Ratings	Unit
Gate-to-Drain Voltage	V_{GDO}		-20	V
Gate Current	I_G		10	mA
Drain Current	I_D		1	mA
Allowable Power Dissipation	P_D		100	mW
Junction Temperature	T_j		150	$^\circ\text{C}$
Storage Temperature	T_{stg}		-55 to +150	$^\circ\text{C}$

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

Package Dimensions

unit : mm (typ)

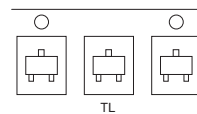
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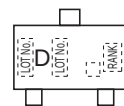
Product & Package Information

- Package : VTFP
- JEITA, JEDEC : SC-106A
- Minimum Packing Quantity : 8,000 pcs./reel

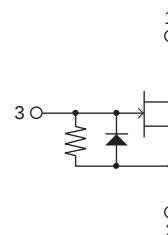
Packing Type: TL



Marking



Electrical Connection



TF252TH

Electrical Characteristics at Ta=25°C

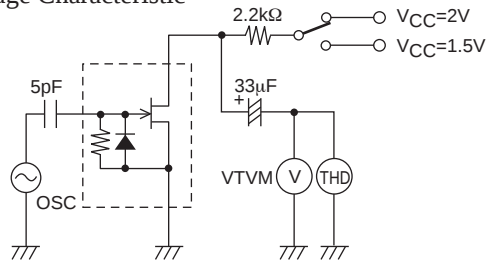
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Gate-to-Drain Breakdown Voltage	V(BR)GDO	I _G =-100μA	-20			V
Cutoff Voltage	V _{GS(off)}	V _{DS} =2V, I _D =1μA	-0.1	-0.4	-1.0	V
Drain Current	I _{DSS}	V _{DS} =2V, V _{GS} =0V	140*		350*	μA
Forward Transfer Admittance	y _{fs}	V _{DS} =2V, V _{GS} =0V, f=1kHz	0.8	1.4		mS
Input Capacitance	C _{iss}	V _{DS} =2V, V _{GS} =0V, f=1MHz		3.1		pF
Reverse Transfer Capacitance	C _{rss}			0.95		pF
[Ta=25°C, V _{CC} =2.0V, R _L =2.2kΩ, C _{in} =5pF, See specified Test Circuit.]						
Voltage Gain	G _V	V _{IN} =10mV, f=1kHz		1.0		dB
Reduced Voltage Characteristic	ΔG _{VV}	V _{IN} =10mV, f=1kHz, V _{CC} =2.0V → 1.5V		-0.6	-2.0	dB
Frequency Characteristic	ΔG _{vf}	f=1kHz to 110Hz			-1.0	dB
Total Harmonic Distortion	THD	V _{IN} =30mV, f=1kHz		0.65		%
Output Noise Voltage	V _{NO}	V _{IN} =0V, A curve		-106	-102	dB

* : The TF252TH is classified by I_{DSS} as follows : (unit : μA)

Rank	4	5
I_{DSS}	140 to 240	210 to 350

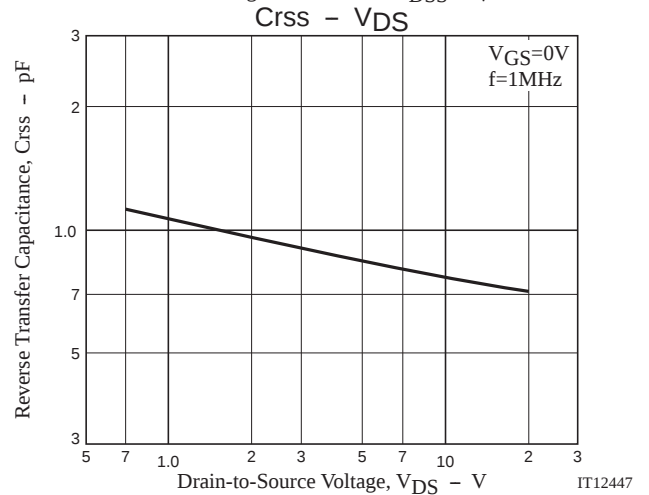
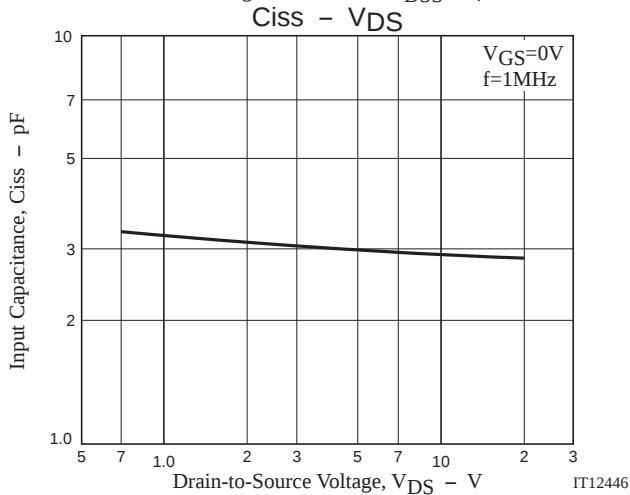
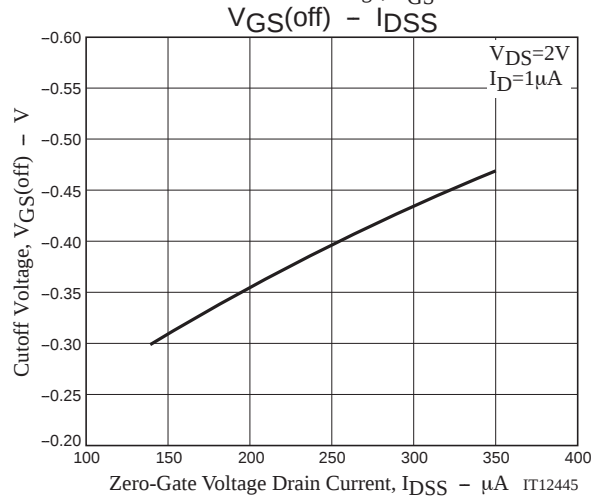
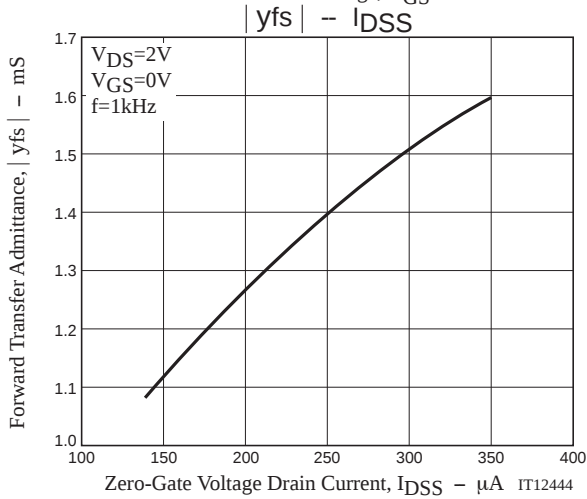
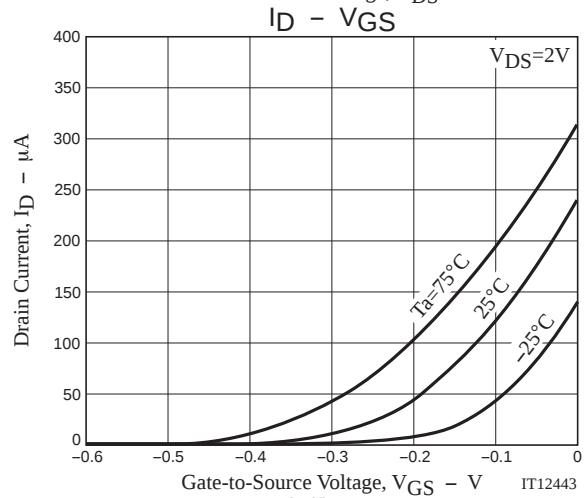
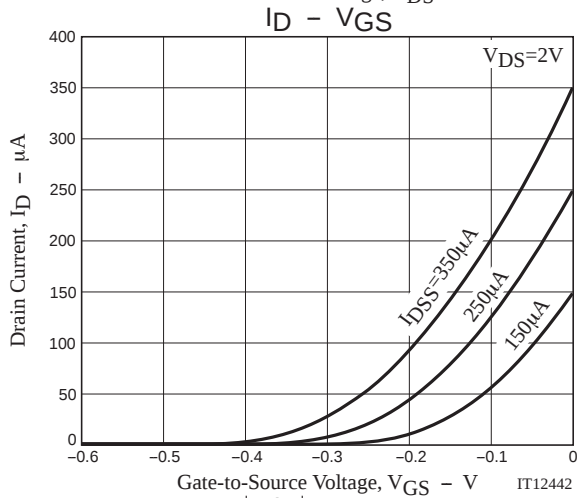
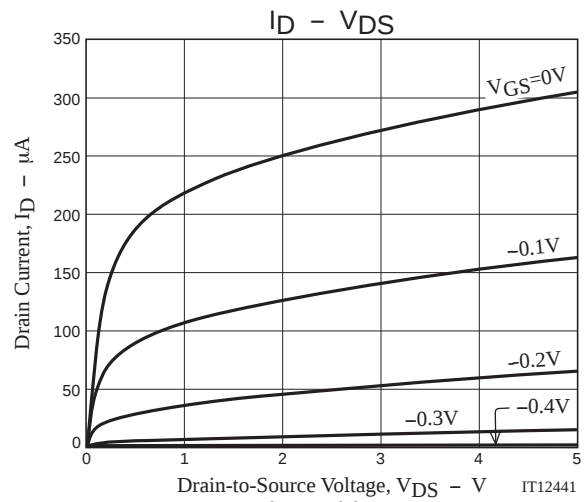
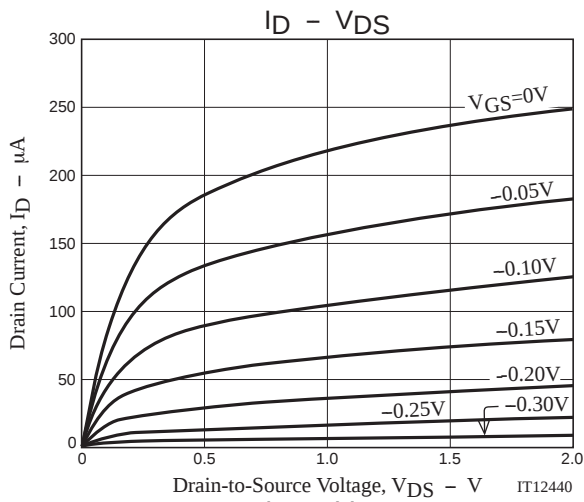
Test Circuit

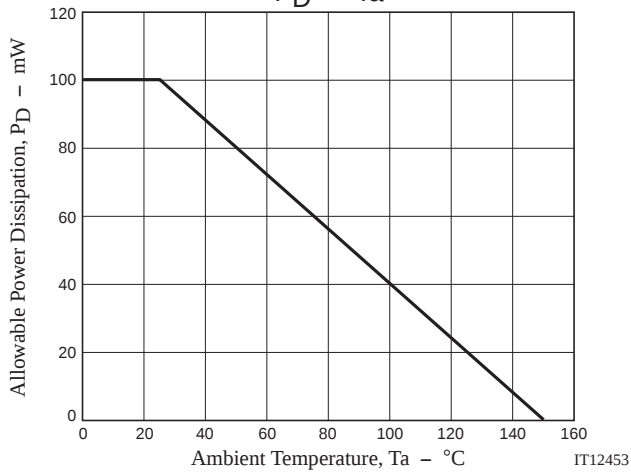
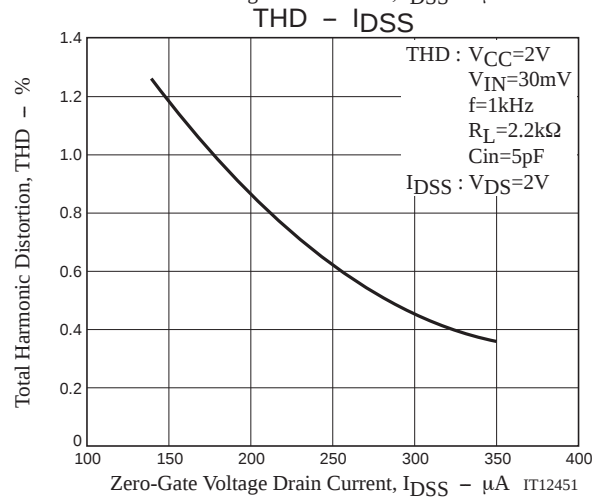
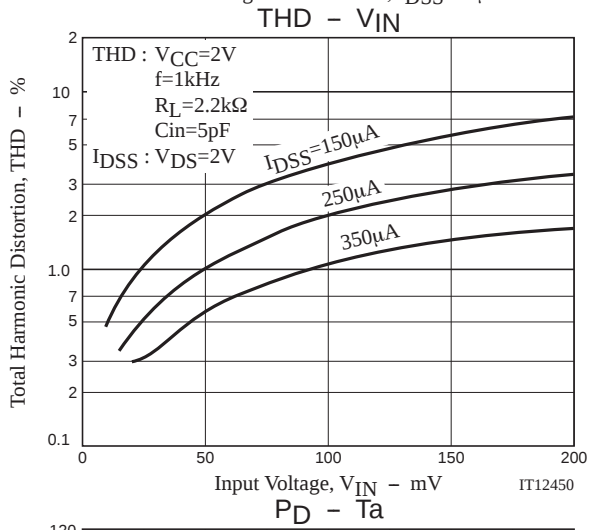
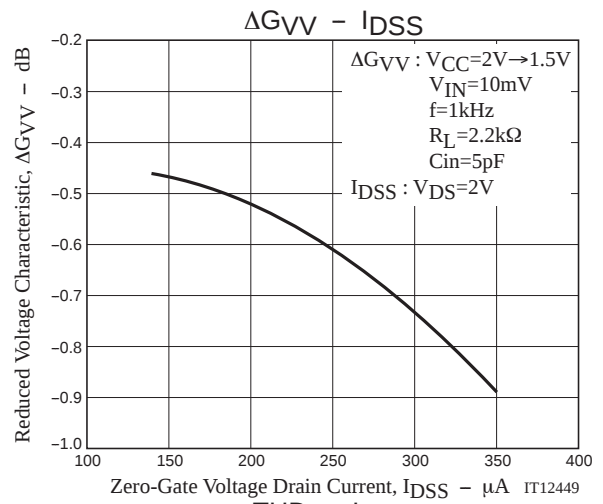
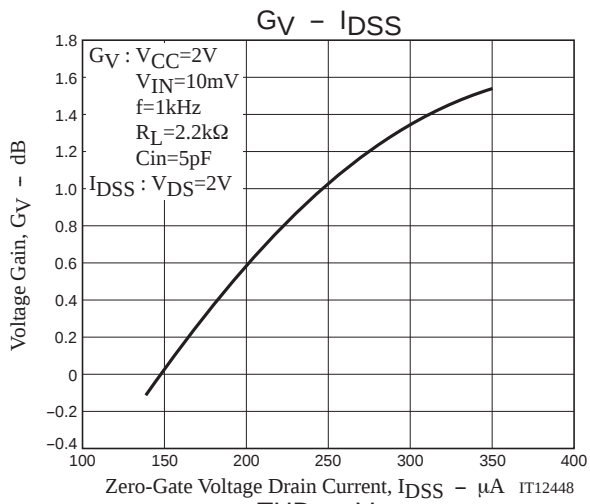
Voltage gain
Frequency Characteristic
Distortion
Reduced Voltage Characteristic



Ordering Information

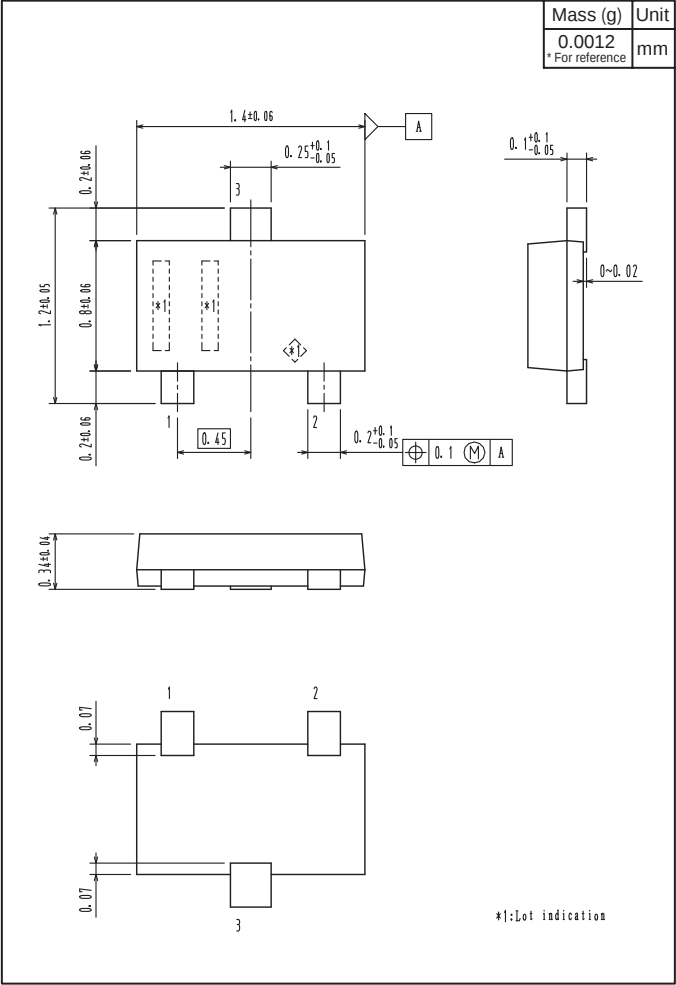
Device	Package	Shipping	memo
TF252TH-4-TL-H	VTFP	8,000pcs./reel	Pb Free and Halogen Free
TF252TH-5-TL-H	VTFP	8,000pcs./reel	



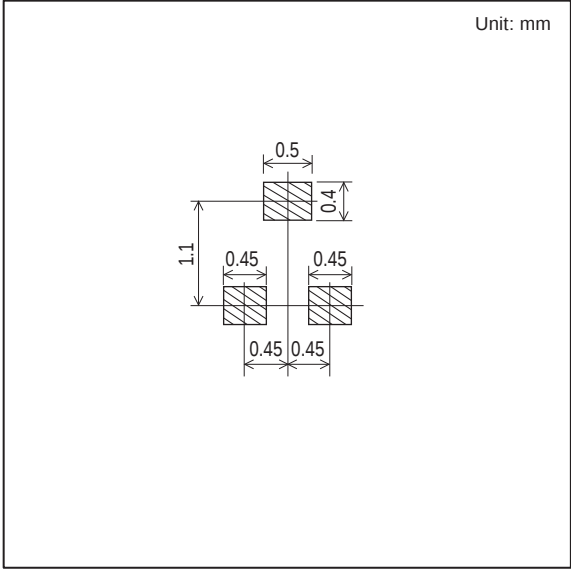


Outline Drawing

TF252TH-4-TL-H, TF252TH-5-TL-H



Land Pattern Example



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